NSN 5961-01-165-5162

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-165-5162 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-72 **Internal Junction Configuration:** Npn **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 12.0 collector to emitter voltage/static/base open and 20.0 collector to base voltage, dc and 2.5 emitter to base voltage, instantaneous **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 300.0 milliwatts small-signal input power, common-collector absolute **Transfer Ratio:** 250.0 static forward current transfer ratio, common-emitter **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**